NSN 5961-01-073-6651

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View Online at https://aerobasegroup.com/nsn/5961-01-073-6651 **Inclosure Material:** Metal **Overall Length:** 1.195 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-61 **Mounting Method:** Threaded stud **Features Provided:** Burn in and hermetically sealed case **Overall Width Across Flats:** 0.677 inches **Thread Size:** 0.250 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 160.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 12.00 amperes source cutoff current and 6.00 amperes source cutoff current **Power Rating Per Characteristic:** 80.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 200.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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